



## Regular Article

## Hot-pressed chromium doped zinc sulfide infrared transparent ceramics

Yiyu Li<sup>a</sup>, Yin Liu<sup>a</sup>, Vladimir V. Fedorov<sup>b</sup>, Sergey B. Mirov<sup>b</sup>, Yiquan Wu<sup>a,\*</sup><sup>a</sup> Kazuo Inamori School of Engineering, New York State College of Ceramics, Alfred University, Alfred, NY 14802, USA<sup>b</sup> Center for Optical Sensors and Spectroscopies, Department of Physics, University of Alabama at Birmingham, CH 310, 1300 University Blvd., Birmingham, AL 35294, USA

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## ABSTRACT

The present study, for the first time, reports the successful consolidation of chromium doped zinc sulfide (ZnS) polycrystalline infrared (IR) transparent ceramics (maximum transmittance of 67% at 11.6  $\mu\text{m}$ ) via hot pressing under vacuum. The phase composition of the as-sintered  $\text{Cr}^{2+}$ :ZnS ceramics was determined to be primarily cubic ZnS sphalerite, with a minor amount of hexagonal ZnS wurtzite. Scanning electron microscopy (SEM) observation of the sintered ceramics showed a highly consolidated microstructure. IR absorption and photoluminescence measurements revealed that the  $\text{Cr}^{2+}$  ions are tetrahedrally coordinated within the ZnS host lattice.

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As an extensively characterized II–VI wide bandgap semiconductor, zinc sulfide has been of significant interest for a long time due to its promising applications in various fields, including optical ceramics, phosphors, quantum dots, photocatalysts, and sensors [1–4]. When doped with transition metals and rare earth elements, ZnS can exhibit a wide range of luminescence behaviors in the visible and infrared regions [5–9]. In addition, due its exceptional performance as a material for room-temperature tunable solid state laser gain media in the mid-IR region, transition metal doped ZnS has inspired a tremendous amount of interest for researchers in past decades.

In 1996, researchers at Lawrence Livermore National Laboratory demonstrated the potential of divalent transition metal doped zinc chalcogenides as materials for mid-IR laser applications [10]. Various divalent transition metals ( $\text{Co}^{2+}$ ,  $\text{Ni}^{2+}$ ,  $\text{Fe}^{2+}$  and  $\text{Cr}^{2+}$ ) were doped into ZnS/ZnSe/ZnTe hosts, and their room temperature mid-IR lasing performances were examined. It was determined that the tetrahedral substitution sites, rather than the octahedral sites, are more favorable doping sites for transition metals in the zinc chalcogenides. The tetrahedral coordination of dopants might contribute to the observed intense low-energy transitions, due to small crystal field splitting. Among the Zn chalcogenides,  $\text{Cr}^{2+}$  doped ZnS/ZnSe showed exceptionally strong room-temperature absorption and emission in the mid-IR region. In addition, temperature-dependent lifetime measurements indicated that these materials revealed high (close to 80 and 100% for Cr:ZnS and Cr:ZnSe, respectively) luminescence quantum yield at room temperature due to weak non-radiative relaxation process [1,2]. It was

demonstrated that  $\text{Cr}^{2+}$  doped ZnS/ZnSe crystals were the most promising candidates for room-temperature tunable mid-IR laser applications. Since then, chromium doped ZnS has attracted more and more extensive attention.

Mirov et al. have conducted tremendous research on the lasing performances of  $\text{Cr}^{2+}$ :ZnS materials [11–14]. It has been reported that they applied chemical vapor transport (CVT) methods followed by thermal diffusion to fabricate  $\text{Cr}^{2+}$ :ZnS transparent ceramic microchips with desirable lasing performances (optical and slope efficiency) [15]. It was also demonstrated by Wang et al. that  $\text{Cr}^{2+}$ :ZnS thin films with promising properties for mid-IR applications could be prepared by pulsed laser deposition [16]. In addition, Martyshkin et al. investigated and demonstrated the effective photoluminescence and lasing properties of  $\text{Cr}^{2+}$ :ZnS nanoparticles in the mid-IR region [17]. Meanwhile, by using Cr:ZnS single crystals, Tolstik et al. obtained Kerr-Lens passive mode-locked Cr:ZnS femtosecond lasers, with distinguished pulse duration and energy [18,19]. The output characteristics of Kerr-lens-mode-locking were significantly improved in [20–22] with the use of Cr:ZnS polycrystalline gain media. Besides studying the lasing performance of  $\text{Cr}^{2+}$ :ZnS, a significant amount of research has been conducted towards understanding the material, including the theory surrounding its crystal field splitting and local structure, as well as its potential applications in other fields such as cathodoluminescence and solar cell applications [23–26].

The most commonly reported method to fabricate  $\text{Cr}^{2+}$ :ZnS transparent materials for laser applications is CVT method followed by thermal diffusion [27]. In addition, based on the method employed to process ZnS transparent ceramics, CVD combined with hot isostatic press (HIP) has also been used to prepare polycrystalline ZnS host ceramics prior to the thermal diffusion of  $\text{Cr}^{2+}$  ions [28]. However, these

\* Corresponding author at: Kazuo Inamori School of Engineering, New York State College of Ceramics, Alfred University, 2 Pine Street, Alfred, NY 14802, USA.

E-mail address: [wuy@alfred.edu](mailto:wuy@alfred.edu) (Y. Wu).

methods are expensive and time-consuming, and have poor repeatability. As a common consolidation method, it is well known that hot pressing has been proven to be an effective and viable way to prepare various optically transparent non-oxide and oxide ceramics, such as ZnS, CaF<sub>2</sub>, Y<sub>2</sub>O<sub>3</sub>, Lu<sub>2</sub>O<sub>3</sub>, and MgAl<sub>2</sub>O<sub>4</sub> [29–36]. It has also been demonstrated that Cr<sup>2+</sup>:ZnSe transparent ceramics with suitable properties for laser applications can be fabricated via hot pressing [37]. However, few studies have been reported on the hot pressing of Cr<sup>2+</sup>:ZnS transparent ceramics.

In the present study, Cr<sup>2+</sup>:ZnS IR transparent ceramics were fabricated via high vacuum hot pressing (VHP) using homogeneous ZnS powders synthesized using a wet chemical precipitation route, which were subsequently mixed with commercially sourced Cr<sub>2</sub>S<sub>3</sub> powders. It was determined that the sintered Cr<sup>2+</sup>:ZnS ceramics were primarily composed of cubic sphalerite phase, with hexagonal wurtzite as a minor phase. The ceramics were studied using SEM, and found to be well-consolidated and highly dense. The spectroscopic properties of the material were characterized to investigate the mid-IR absorption and photoluminescence behavior induced by doping with Cr<sup>2+</sup>.

The synthesis of ZnS powders was performed through a facile colloidal processing method, which was reported in our previous studies [31]. Aqueous solutions of thioacetamide (TAA, ≥99.0%, Sigma Aldrich) and Zn(NO<sub>3</sub>)<sub>2</sub>·6H<sub>2</sub>O (≥99.0%, Sigma Aldrich) with stoichiometric ratios of Zn:S were mixed together by stirring, and HNO<sub>3</sub> (70%, Sigma Aldrich) was added to the mixed solution to adjust pH to 2. The solution was then heated in a hot water bath to encourage particle growth. After sufficient time, the suspension of ZnS colloids was cooled in an ice water bath to halt particle growth. The precipitates were then washed by both DI water and ethanol (Reagent alcohol, 100%, Decon) to remove reaction residues, and then dried in an oven in air. The precipitates were then finely ground and mixed with an addition of 0.1 mol% Cr<sub>2</sub>S<sub>3</sub> (99%, Alfa Aesar) in an agate mortar and pestle. The mixed powders were then heat treated at 900 °C for 4 h in flowing argon to prepare for sintering. The ceramic samples were prepared for VHP by loading the powders into a graphite die with a diameter of 10 mm, with layers of graphite foil (thickness of 0.5 mm) used to separate the sample powders from the punches. The powders were consolidated at 1000 °C for 2 h under a uniaxial pressure of 50 MPa under a vacuum of 10<sup>-5</sup> mbar (OTF-1200X-VHP4, MTI).

The phase composition of the sintered Cr<sup>2+</sup>:ZnS ceramics was determined using XRD (Bruker D2 PHASER) with Cu Kα (λ = 0.154 nm) radiation at a voltage of 30 kV and a current of 10 mA. Measurement conditions of 0.03°2θ step size and 0.2 s count time were employed over a measurement range of 10–75°2θ. The morphological and structural features of the Cr:ZnS powders and sintered ceramics were investigated by SEM (FEI Quanta 200) at an accelerating voltage of 20 kV. Archimedes method density measurements were adopted to determine the density of the as-sintered ceramics. The IR transmittance of the polished pellet was measured using FTIR (Nicolet 6700, Thermo Fisher). Photoluminescence spectra and kinetics characterizations were performed using an acousto-optically Q-switched Er:YAG laser under an

excitation at 1.645 μm with ~60 ns pulse duration. Photoluminescence spectra were collected by using a monochromator (Acton Research ARC-300i). A Thorlabs PDA 20H PbSe detector, in addition to a fast PVI-3TE-5 (HgCdTe, VIGO systems) detector with a response time of ~200 ns were employed for signal detection. A polycrystalline Cr<sup>2+</sup>:ZnS sample with a chromium concentration of 8 · 10<sup>18</sup> cm<sup>-3</sup>, fabricated by a post-growth thermal diffusion method [12], was used for the comparison of optical properties with the Cr<sup>2+</sup>:ZnS ceramics.

Fig. 1 (a) shows the SEM image of the synthesized ZnS powders mixed with a 0.1 mol% addition of Cr<sub>2</sub>S<sub>3</sub> powders. The powders appear to be composed of well-dispersed, homogenous, spherical particles with a size of approximately 100–200 nm, the small size of which is attributed to the use of both hot and cold water baths to achieve better control of particle growth during colloidal processing. The microstructure of the thermally etched surface of the polished Cr<sup>2+</sup>:ZnS ceramics is shown in Fig. 1 (b). It can be observed that the VHP-consolidated ceramics have an average grain size of about 1–2 μm and is highly dense, likely due to the homogenous morphology of the raw powders and the effectiveness of applied VHP technique. The relative density was measured to be 98.8%, which is in agreement with SEM observations of a highly consolidated microstructure. Fig. 1 (c) displays the XRD pattern of the Cr<sup>2+</sup>:ZnS ceramics consolidated via VHP. The sample is composed of a mixture of mainly cubic sphalerite (JCPDS no: 65-5476; F-43 m; a = 5.40 Å) with a small amount of hexagonal wurtzite (JCPDS no: 02-1310; P63mc; a = 3.82 Å, c = 6.25 Å). In addition, no Cr<sub>2</sub>S<sub>3</sub> impurity peaks can be detected in the XRD measurement because of the low added level of Cr<sub>2</sub>S<sub>3</sub>. Due to the high surface energy of the small particles of the raw powders, during consolidation the Cr<sup>2+</sup>:ZnS ceramics experience an early phase transition from the cubic phase to hexagonal phase at 1000 °C, which is lower than the reported phase transition temperature of 1020 °C.

Fig. 2 (a) shows the IR transmittance curve of a polished Cr<sup>2+</sup>:ZnS ceramic pellet, obtained by FTIR measurement over a wavelength range of 2.5–16.0 μm. Due to the effective consolidation via VHP, the Cr<sup>2+</sup>:ZnS polycrystalline ceramic sample exhibits high transmittance in the IR region, with a maximum transmittance of 67% at 11.6 μm, while the theoretical maximum transmittance according to the Fresnel equations is 75% in the IR range. It is important to note that the transmission curve shape near the IR edge is very similar for the VHP-consolidated ceramic sample and the polycrystalline sample fabricated via the post-growth thermal diffusion method. The reduced transmission observed in the VHP-consolidated ceramic sample in the near-IR spectral range is likely due to scattering effects within the ceramic. As can be observed from the inset photo, the sample is translucent even in the visible region, with the green color of the sample believed to result from the incorporation of Cr<sup>2+</sup> ions into the ZnS lattice. Based on comparison of spectra from measurement of the samples and measurement of the ambient atmosphere, it is determined that the absorption peaks in the 3.2–7.0 μm range are due to atmospheric absorptions. Specifically, the absorption bands between 3.4, 3.5 and 4.2 μm are attributed to water adsorbed from the atmosphere, and the small peaks at 5.7, 6.2

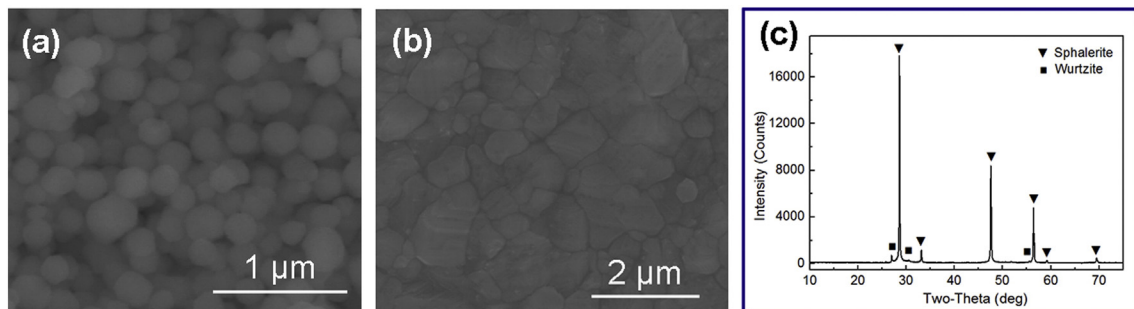


Fig. 1. (a) SEM image of the synthesized ZnS powders mixed with 0.1 mol% Cr<sub>2</sub>S<sub>3</sub> powders. (b) SEM image of the thermally etched surface of the VHP-sintered Cr<sup>2+</sup>:ZnS ceramics. (c) XRD pattern of the Cr<sup>2+</sup>:ZnS ceramics consolidated via VHP.

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